



ÉCOLE POLYTECHNIQUE
FÉDÉRALE DE LAUSANNE



Photovoltaics for H₂ Production

D. Dominé, L. Löfgren, J.-H. Yum, P. Kohler,
M. Benkhaira, L. Sansonnens, S. Nicolay and J. Bailat

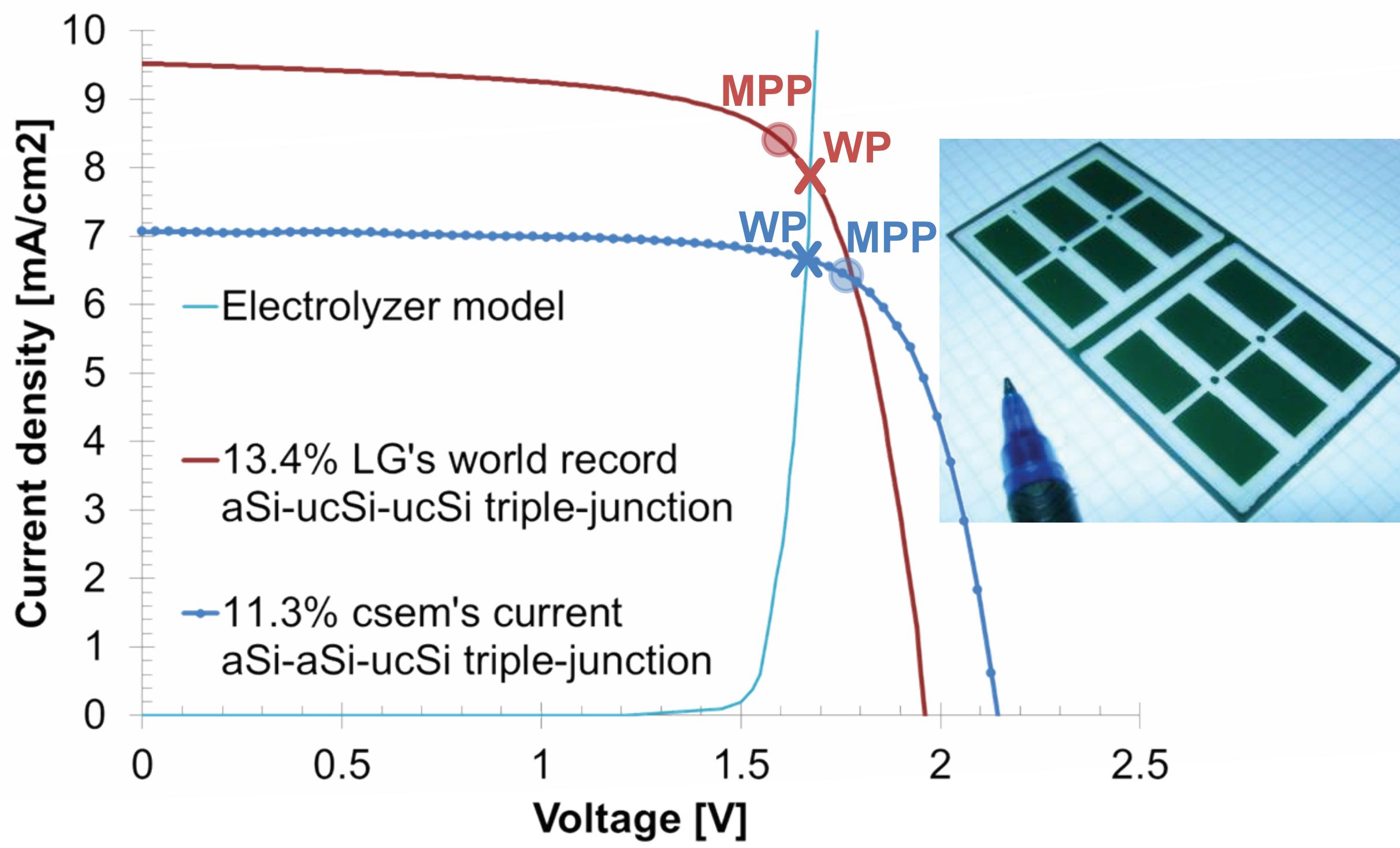
CSEM SA, Switzerland, info@csem.ch



Materials Science & Technology



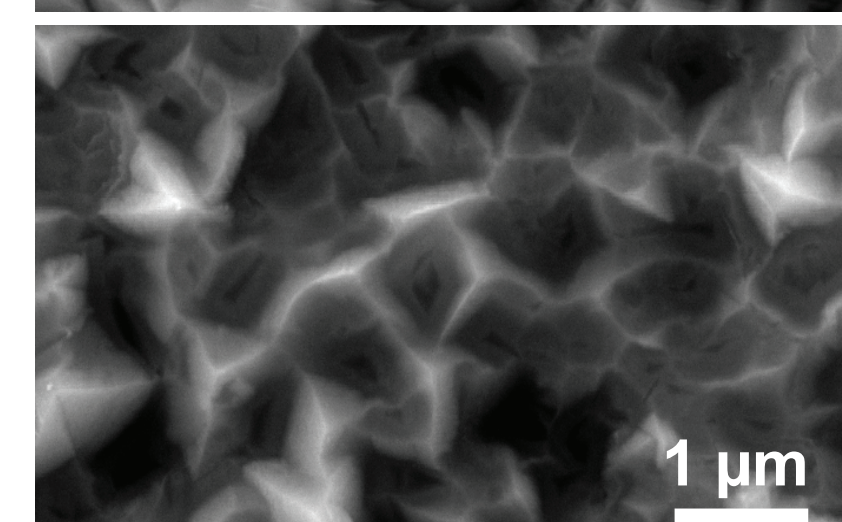
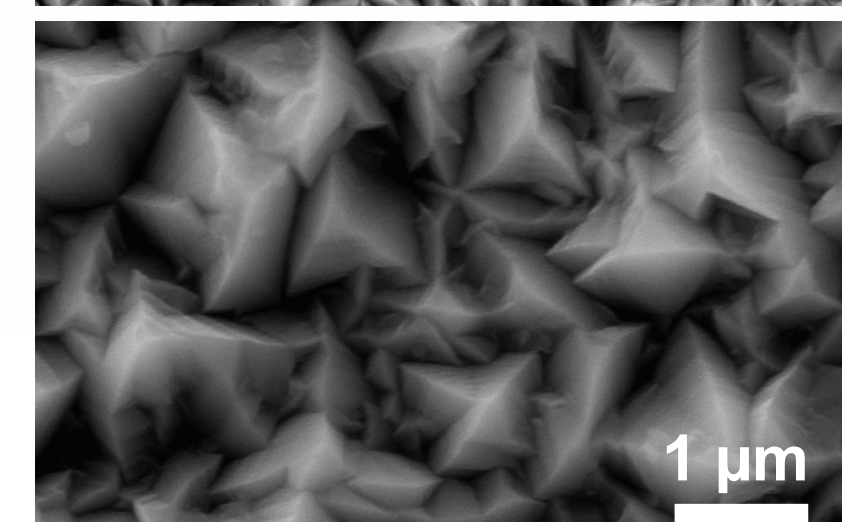
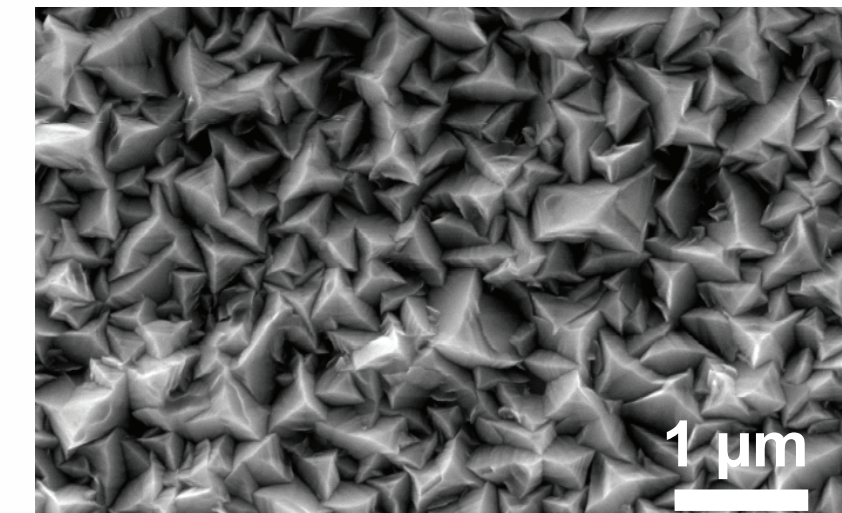
PV cell & electrolyzer: working point (WP)



- PV device must provide the voltage to break water molecules: open-circuit voltage $V_{oc} > 2 V$;
- Stable working point at the left of the maximum power point (MPP) of the PV device. → OK for csem's device.

Thin-film PV technologies from EPFL PV-lab

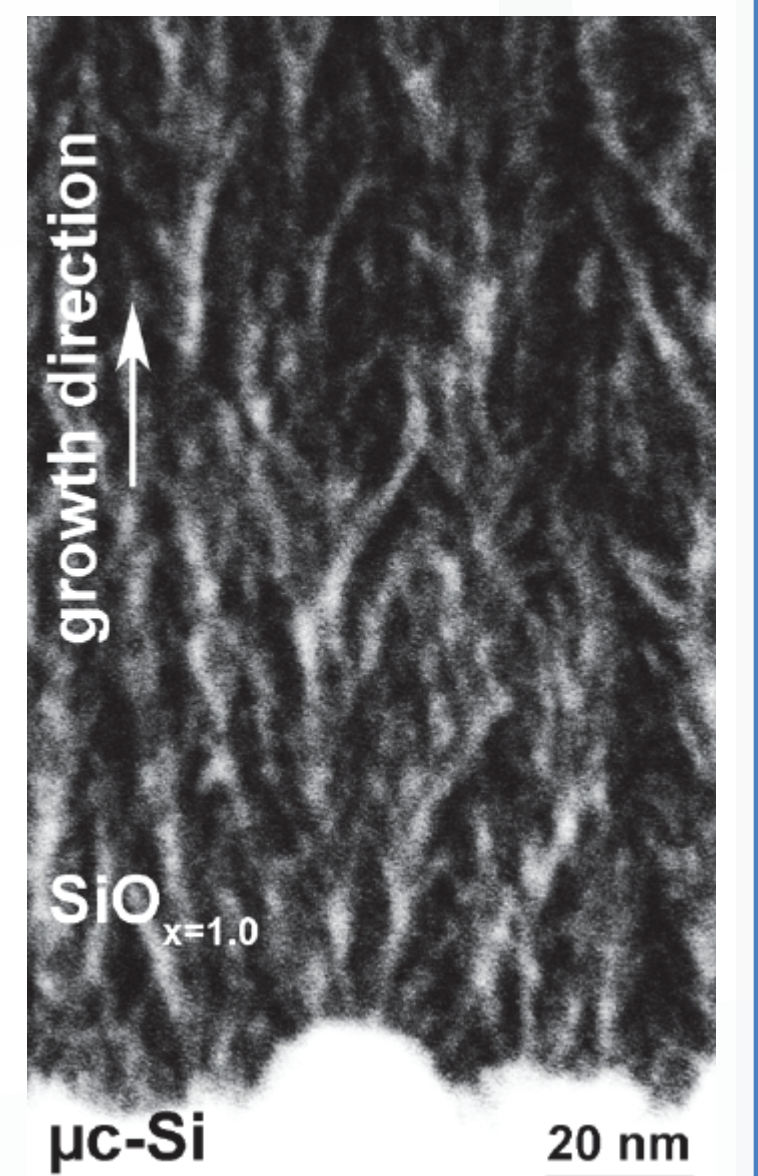
- Non-toxic and earth abundant materials ;
- Control of the surface morphology of zinc oxide transparent electrodes → light-trapping via diffuse scattering.



SEM pictures of the surface of (a) 2 μm and (b,c) 5 μm thick LPCVD ZnO layers without (a,b) and with (c) a surface treatment with Ar plasma.

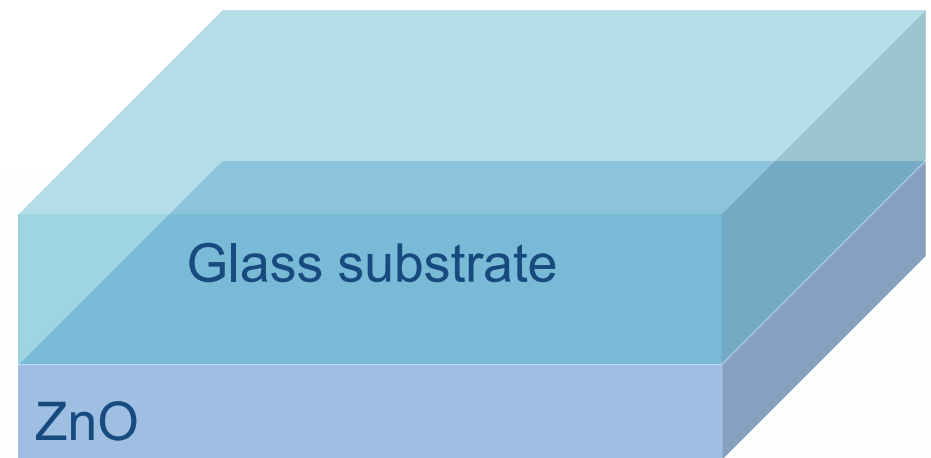
- Electronic transport through SiO_x reflectors via dendritic silicon filaments.

Cross-section EFTEM picture of a SiO_x film with refractive index of 1.8 and heavily doped Si dendrites [P. Cuony et al., *Adv. Mater.* 2012].



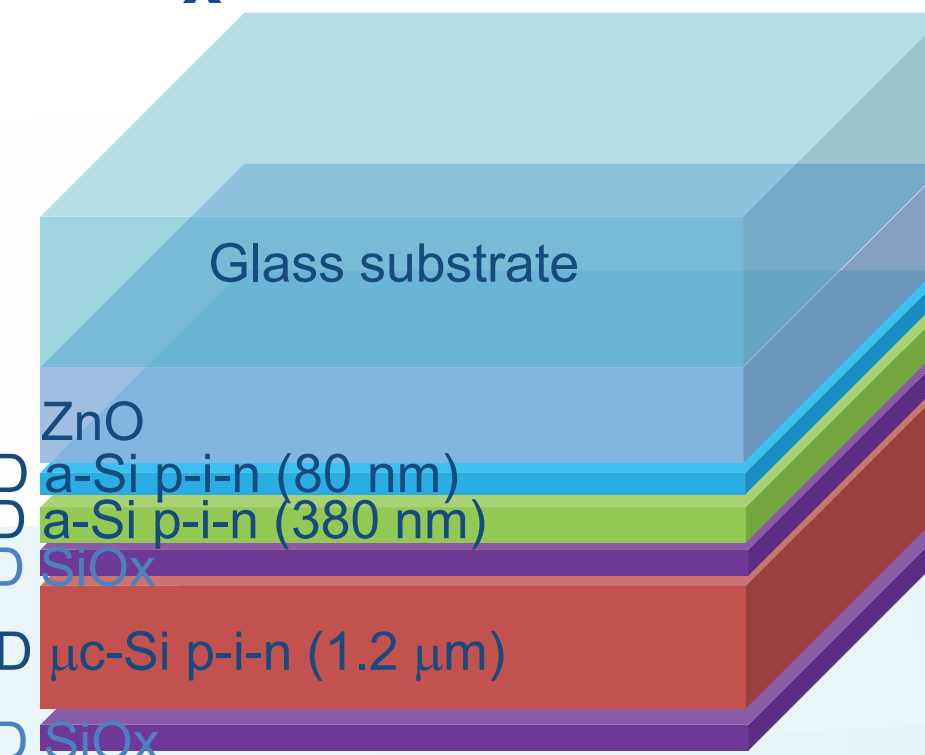
Fabrication flow for thin-film silicon triple-junction solar cells and photocathodes

Zinc oxide Front transparent contact



ZnO on glass substrate by low pressure chemical vapor deposition (LPCVD)

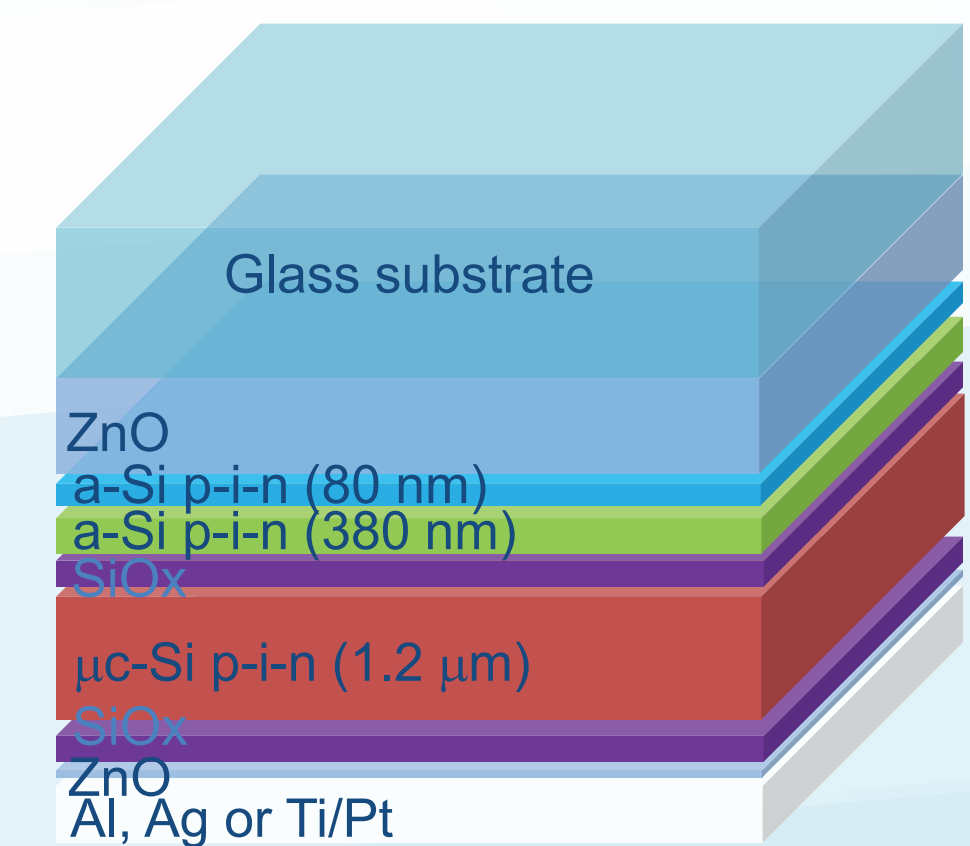
Thin film silicon p-i-n junctions and SiO_x with silicon filaments



Top cell: PECVD a-Si p-i-n (80 nm)
Middle cell: PECVD a-Si p-i-n (380 nm)
Intermediate reflector: PECVD SiO_x
Bottom cell: PECVD μ C-Si p-i-n (1.2 μm)
Back reflector: PECVD SiO_x

Single run of plasma enhanced chemical vapor deposition (PECVD)

Back contact, reflector



Dielectric: LPCVD
Metallic: sputtering, evaporation

Application in PV+electrolyzer configuration

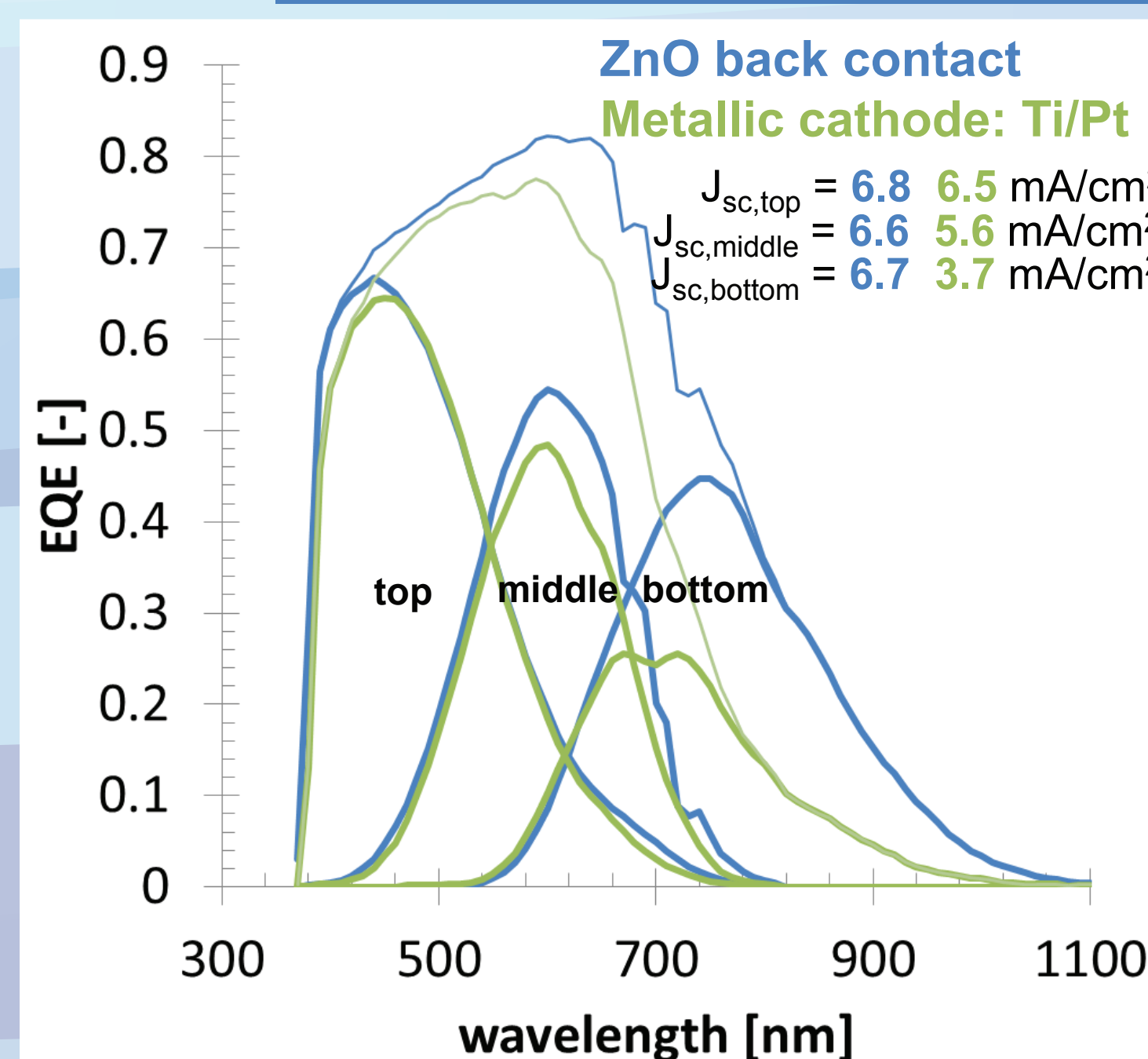
J _{sc} (mA/cm ²)	V _{oc} (mV)	FF (-)	J _{mp} (mA/cm ²)	V _{mp} (mV)	P _{mp} (mW/cm ²)
7.08	2144	0.749	6.41	1773	11.3

Model	Model	Model
J _{WP} (mA/cm ²)	V _{WP} (mV)	P _{WP} (mW/cm ²)
6.68	1654	11.0

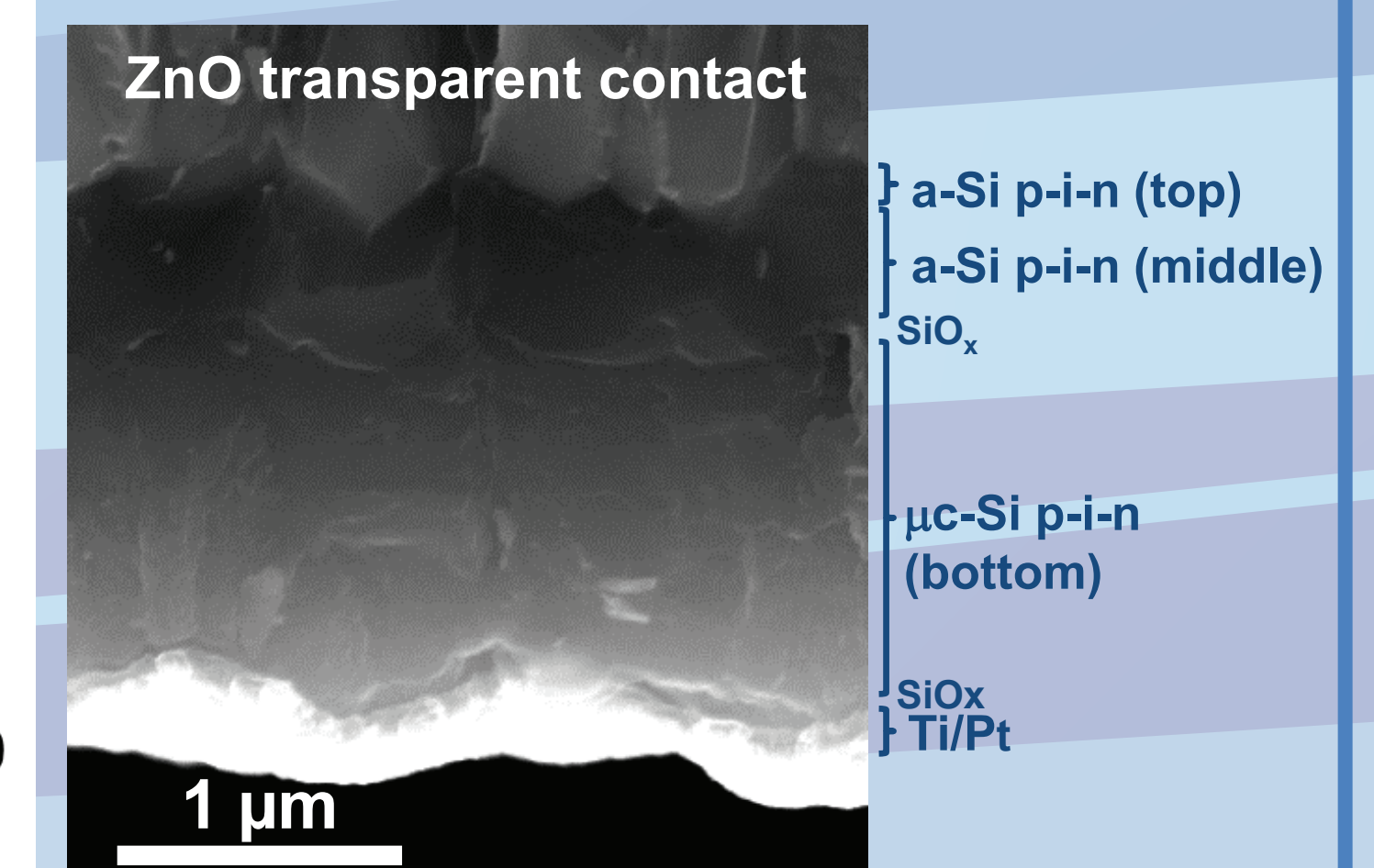
Conclusion:

- Csem's a-Si / a-Si / μ C-Si solar cell with $V_{oc} > 2 V$ allows for direct water splitting ;
- With 100 mW/cm² AM1.5 illumination, availability of 11.3 mW/cm² at MPP and 11.0 mW/cm² at the working point with the modeled electrolyzer.

Application as photocathode



Photocathodic H₂ evolution from direct immersion of the device in acidic solution.



J _{sc} (mA/cm ²)	V _{oc} (mV)	FF (-)	J _{mp} (mA/cm ²)	V _{mp} (mV)	P _{mp} (mW/cm ²)
3.73	2173	0.667	3.07	1760	5.4

Conclusion for the photocathode application:

- Decrease of middle and bottom cell current densities ;
- This is due to the poor reflectivity of the Pt cathode.